

## SOT-143 Plastic-Encapsulate ESD Protection Diodes

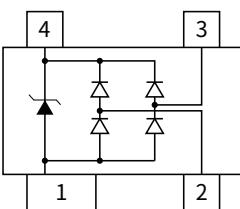
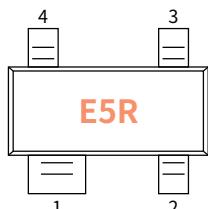
### Features

- Low leakage current
- SOT-143 surface mount package
- IEC 61000-4-2 (ESD Air):  $\pm 25\text{kV}$
- IEC 61000-4-2 (ESD Contact):  $\pm 20\text{kV}$
- IEC 61000-4-5 (Lightning 8/20 $\mu\text{s}$ ): 5A

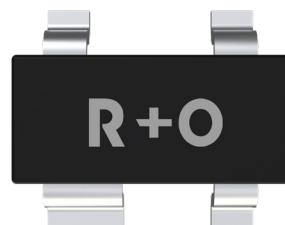
### Applications

- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation, Digital Cameras
- Peripherals, Audio Players
- Industrial Equipment

### Function Diagram



**Reverse Working Voltage**  
5V Max.  
**Ultra small capacitance**  
 $C_{I/O-GND}=0.6\text{pF}(\text{Typ.})$   
 $C_{I/O-I/O}=0.3\text{pF}(\text{Typ.})$

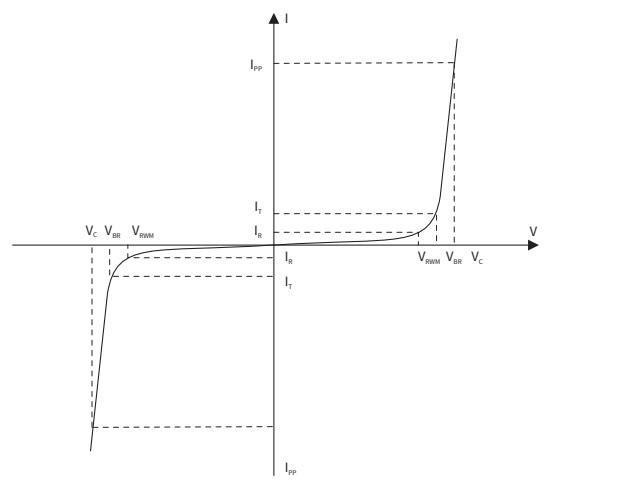
**SOT-143**

### Maximum Ratings (Ta=25°C Unless otherwise specified)

SYMBOL	PARAMETER	CONDITIONS	VALUE	UNIT
$V_{ESD}$	Electrostatic Discharge Voltage	ESD per IEC 61000-4-2( Air )	$\pm 25$	kV
		ESD per IEC 61000-4-2( Contact )	$\pm 20$	kV
$P_{PP}$	Peak Pulse Power	$t_p = 8/20 \mu\text{s}$	75	W
$I_{PP}$	Rated Peak Pulse Current	$t_p = 8/20 \mu\text{s}$	5	A
$T_J$	Operating JunctionTemperature Range	—	-55 to +125	°C
$T_{STG}$	Operating JunctionTemperature Range	—	-55 to +150	°C

### Electrical Parameter

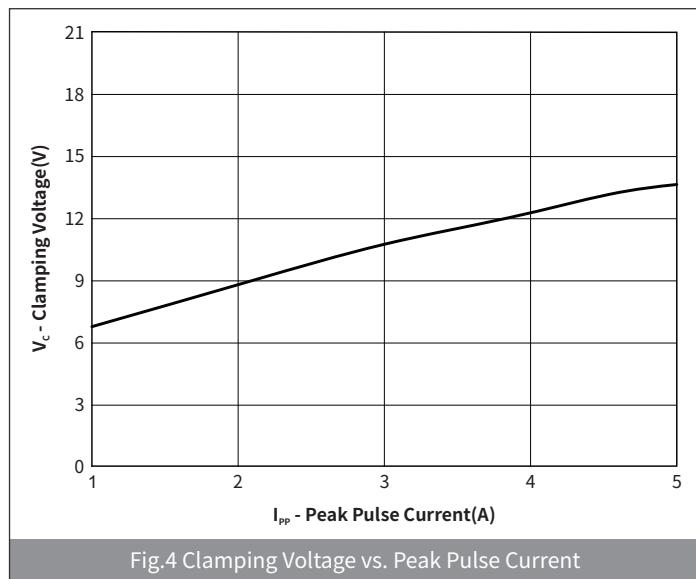
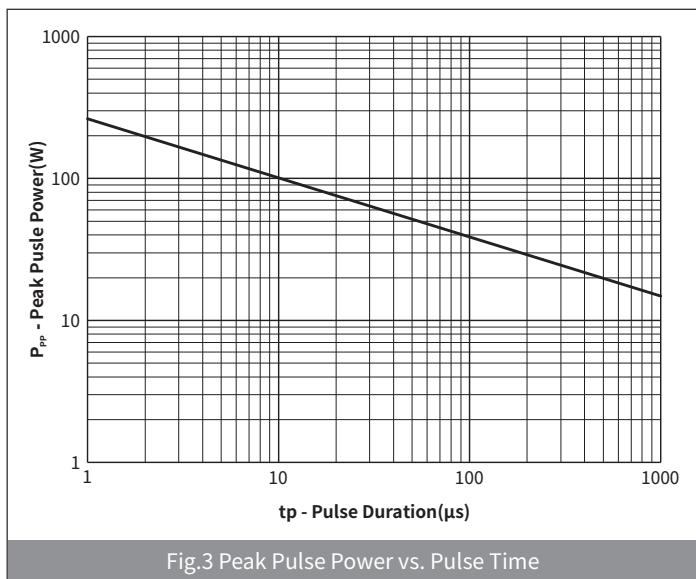
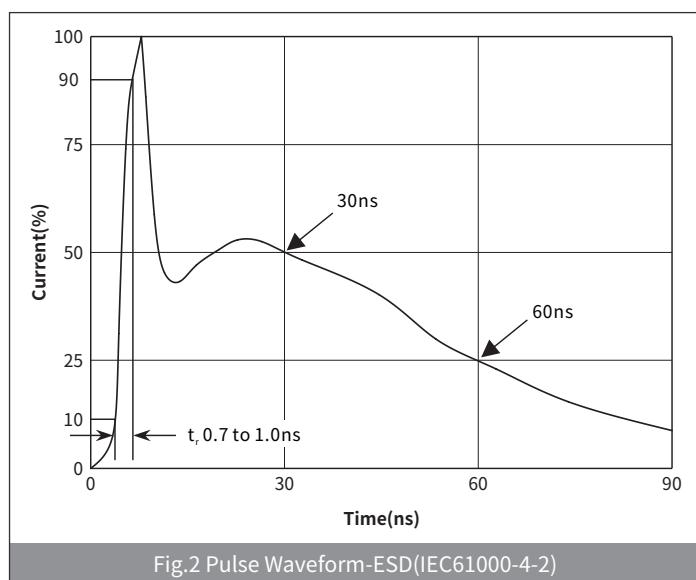
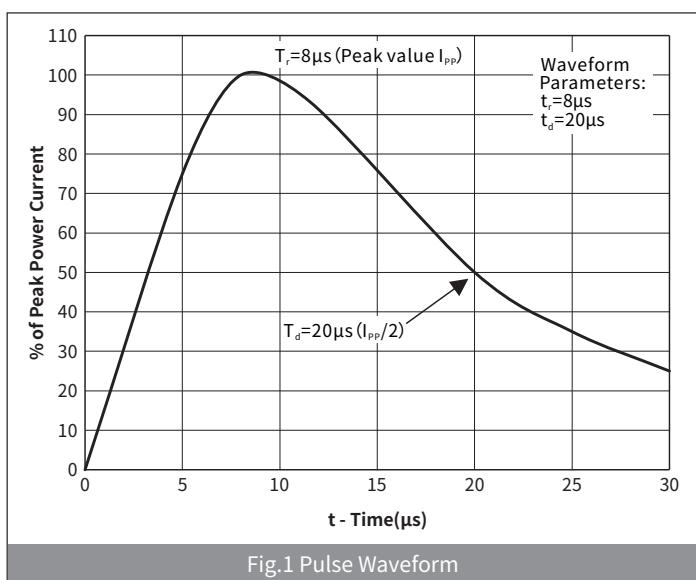
SYMBOL	PARAMETER
$V_C$	Clamping Voltage @ $I_{PP}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_{PP}$	Peak Pulse Current
$I_T$	Test Current
$I_R$	Reverse Leakage Current @ VRWM
$V_{RWM}$	Peak Reverse Working Voltage
$P_{PP}$	Peak Pulse Power Dissipation
$C_J$	Junction Capacitance @ $V_R=0\text{V}, f=1\text{MHz}$
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$



## ● Electrical Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	CONDITION	Min	Typ	Max	UNIT
Peak Reverse Working Voltage	V <sub>RWM</sub>	T <sub>a</sub> =25°C	—	—	5.0	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>R</sub> =1mA, T <sub>a</sub> =25°C	6.0	—	—	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>R</sub> =5V, T <sub>a</sub> =25°C	—	—	0.5	μA
Clamping Voltage	V <sub>C</sub>	I <sub>PP</sub> =1.0A, t <sub>p</sub> =8/20μs	—	—	10	V
		I <sub>PP</sub> =5A, t <sub>p</sub> =8/20μs	—	—	15	
Junction Capacitance	C <sub>J</sub>	V <sub>R</sub> =0V, f=1MHz, I/O Pin to ground	—	0.6	0.8	pF
		V <sub>R</sub> =0V, f=1MHz, Between I/O pins	—	0.3	0.4	

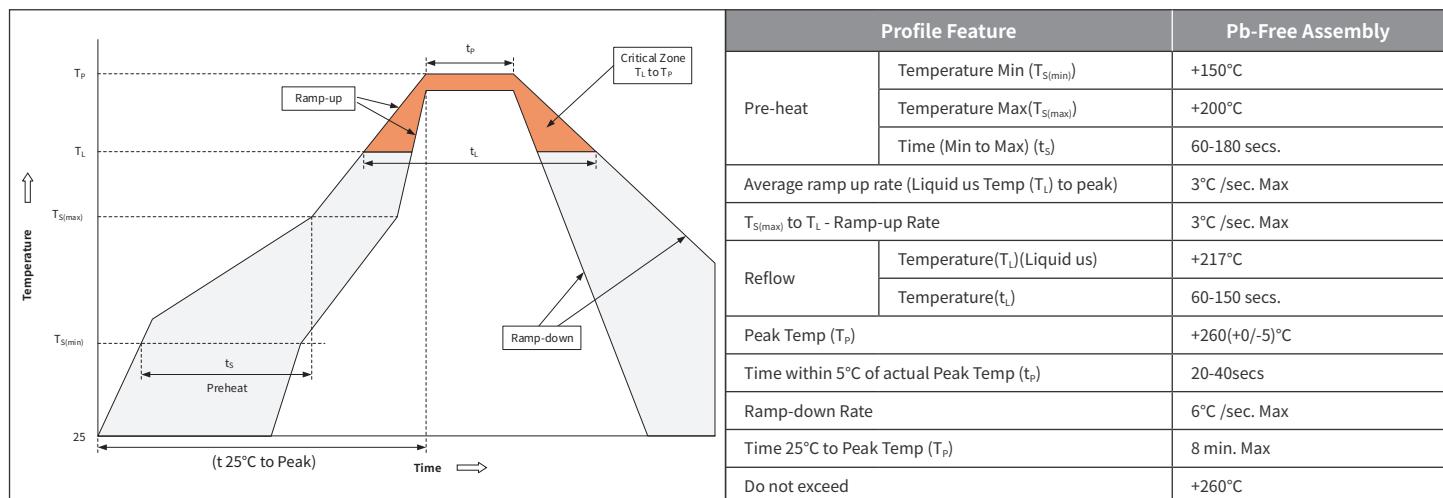
## ● Ratings And Characteristics Curves (Ta=25°C Unless otherwise specified)



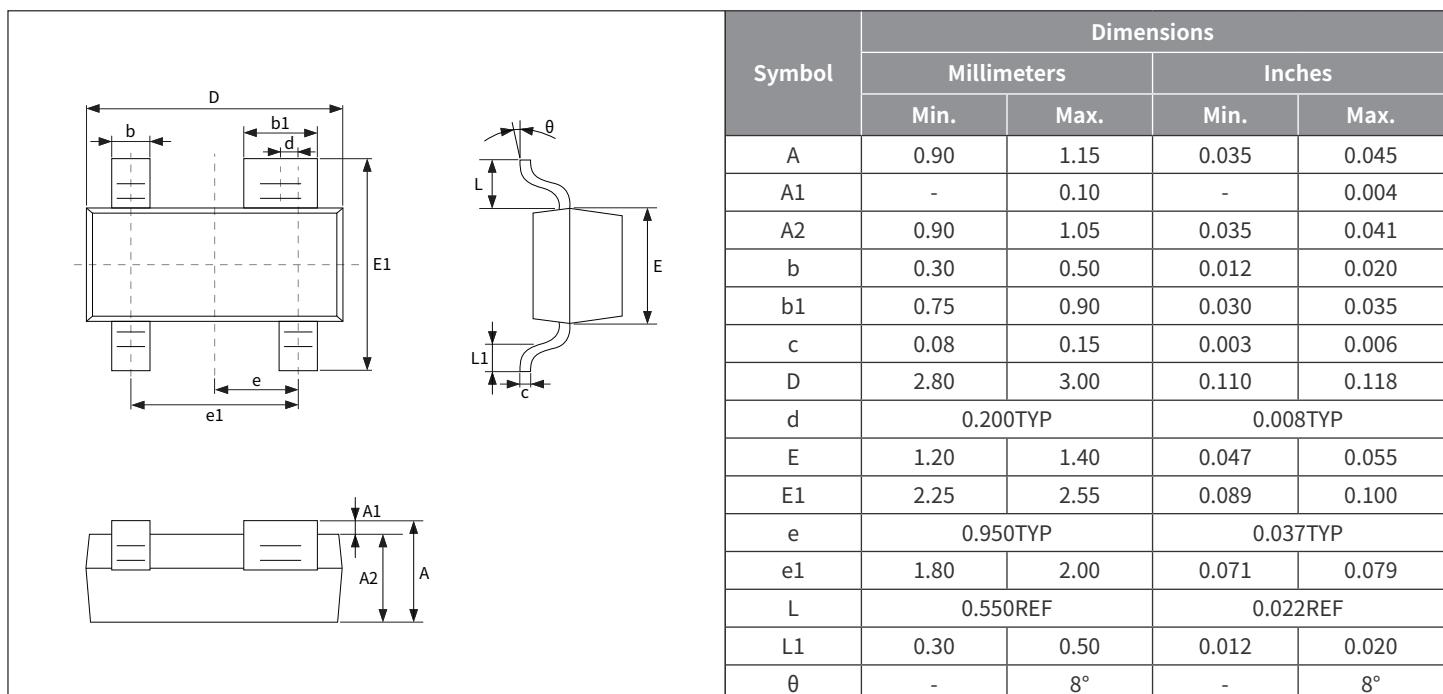
## ● Ordering Information

PREFERRED P/N	PACKAGE	SIZE(mm)	DELIVERY MODE	MPQ(PCS)
H5VUT1B	SOT-143	2.90×2.40×1.025	7" REEL	3000

## ● Recommended Soldering Conditions



## ● Package Outline Dimensions (SOT-143)



## ● Suggested Pad Layout

